OSRAM LB TTSD **Datasheet**

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TOPLED®

LB TTSD

TOPLED, SMT LED with integrated reflector. With our great experience in SMT LED we are able to offer a high quality product for all kind of applications.





Applications

- Functional Illumination

Features

- Package: white PLCC-2 package, colorless clear resin

- Chip technology: ThinGaN

- Typ. Radiation: 120° (Lambertian emitter)

- Color: λ_{dom} = 469 nm (• blue)

- Corrosion Robustness Class: 3B

- Qualifications: AEC-Q102 Qualified

- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM)

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Ordering Information

Type Luminous Intensity 1) Ordering Code

I_F = 20 mA

ľ

LB TTSD-S1T2-25-35 180 ... 450 mcd Q65113A0874



Maximum Ratings			
Parameter	Symbol		Values
Operating Temperature	T _{op}	min. max.	-40 °C 110 °C
Storage Temperature	T_{stg}	min. max.	-40 °C 110 °C
Junction Temperature	T_{j}	max.	125 °C
Forward current T _S = 25 °C	I _F	min. max.	1 mA 30 mA
Surge current t \leq 10 µs; D = 0.005 ; T _s = 25 °C	I _{FS}	max.	200 mA
Reverse voltage ²⁾ T _S = 25 °C	V_R	max.	5 V
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM)	V_{ESD}		2 kV



Characteristics

 I_F = 20 mA; T_S = 25 °C

Parameter	Symbol		Values	
Peak Wavelength	λ_{peak}	typ.	464 nm	
Dominant Wavelength 3)	$\lambda_{\sf dom}$	min.	460 nm	
$I_{\rm r} = 20 \text{ mA}$	dom	typ.	469 nm	
'		max.	476 nm	
Spectral Bandwidth at 50% I _{rel,max}	Δλ	typ.	25 nm	
Viewing angle at 50% I _v	2φ	typ.	120 °	
Forward Voltage 4)	V_{F}	min.	2.60 V	
$I_F = 20 \text{ mA}$	•	typ.	3.00 V	
		max.	3.50 V	
Reverse current ²⁾	I _R	typ.	0.01 μΑ	
$V_R = 5 V$	TX	max.	10 µA	
Real thermal resistance junction/ambient 5)6)	R _{thJA real}	max.	340 K / W	
Real thermal resistance junction/solderpoint 5)	$R_{thJS\ real}$	max.	180 K / W	



Brightness Groups

Group	Luminous Intensity 1) I _F = 20 mA	Luminous Intensity. 1) I _F = 20 mA	Luminous Flux ⁷⁾ I _F = 20 mA
	min.	max.	typ.
	l _v	l _v	Φ _V
S1	180 mcd	224 mcd	590 mlm
S2	224 mcd	280 mcd	730 mlm
T1	280 mcd	355 mcd	920 mlm
T2	355 mcd	450 mcd	1170 mlm

Forward Voltage Groups

Group Forward Voltage $^{4)}$ I _F = 20 mA min. V _F		Forward Voltage ⁴⁾ I _F = 20 mA max. V _F	
3	2.60 V	2.90 V	
4	2.90 V	3.20 V	
5	3.20 V	3.50 V	

Wavelength Groups

Group	Dominant Wavelength ³⁾ I _F = 20 mA	Dominant Wavelength ³⁾ I _F = 20 mA	
	min.	max.	
	$\lambda_{\sf dom}$	$\lambda_{\sf dom}$	
2	460 nm	464 nm	
3	464 nm	468 nm	
4	468 nm	472 nm	
5	472 nm	476 nm	

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Group Name on Label

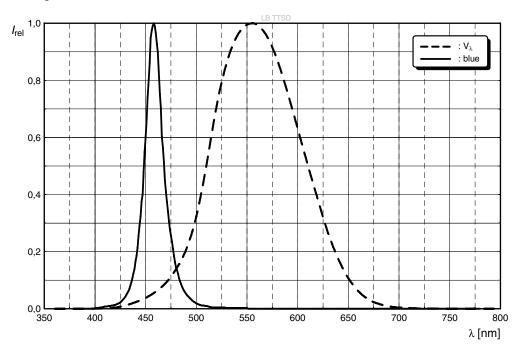
Example: S1-2-3

Brightness	Wavelength	Forward Voltage	
S1	2	3	



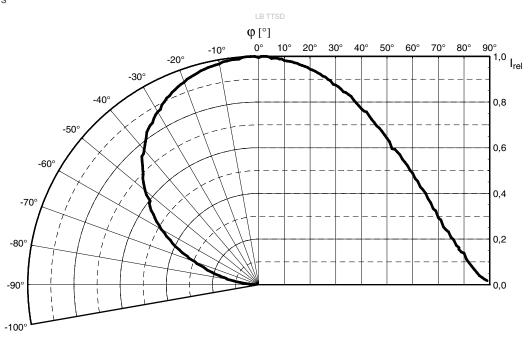
Relative Spectral Emission 7)

 I_{rel} = f (λ); I_{F} = 20 mA; T_{S} = 25 °C



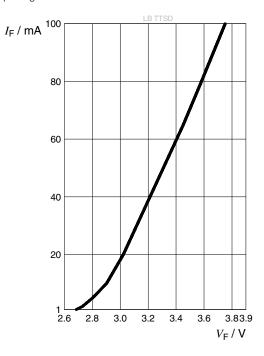
Radiation Characteristics 7)

 $I_{rel} = f(\phi); T_S = 25 °C$



Forward current 7)

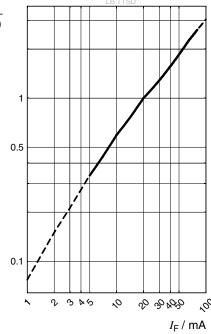
$$I_F = f(V_F); T_S = 25 \, ^{\circ}C$$



Relative Luminous Intensity 7), 8)

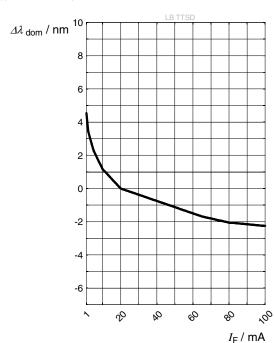
$$I_{v}/I_{v}(20 \text{ mA}) = f(I_{F}); T_{S} = 25 \text{ °C}$$





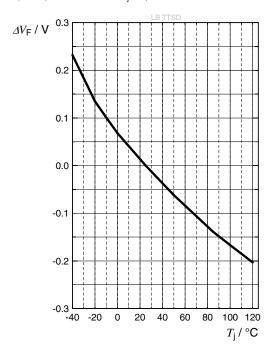
Dominant Wavelength 7)

$$\Delta\lambda_{dom} = f(I_F); T_S = 25 \text{ }^{\circ}\text{C}$$



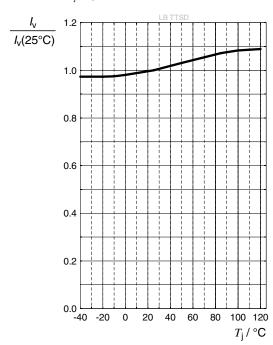
Forward Voltage 7)

$$\Delta V_{_F} = V_{_F} - V_{_F} (25 \ ^{\circ}C) = f(T_{_j}); \ I_{_F} = 20 \ mA$$



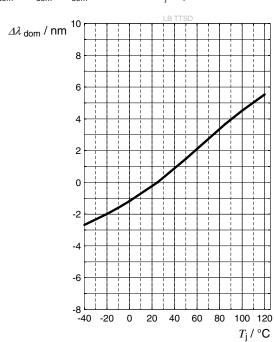
Relative Luminous Intensity 7)

$$I_{v}/I_{v}(25 \text{ °C}) = f(T_{i}); I_{F} = 20 \text{ mA}$$



Dominant Wavelength 7)

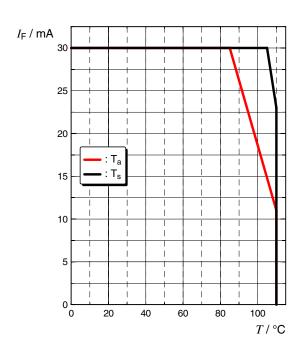
$$\Delta \lambda_{dom} = \lambda_{dom} - \lambda_{dom} (25 \text{ °C}) = f(T_j); I_F = 20 \text{ mA}$$





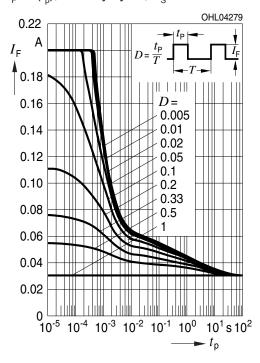
Max. Permissible Forward Current

 $I_F = f(T)$



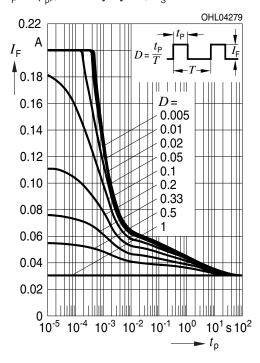
Permissible Pulse Handling Capability

 $I_{_{\rm F}}$ = f($t_{_{
m D}}$); D: Duty cycle; $T_{_{
m S}}$ = 25 °C



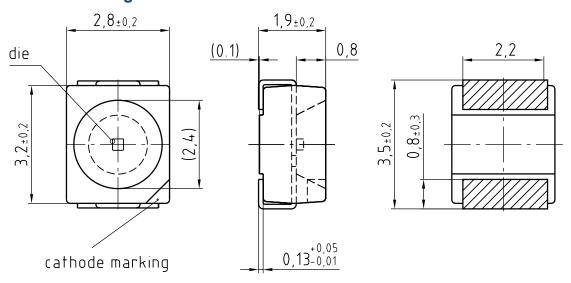
Permissible Pulse Handling Capability

 $I_{_{\rm F}}$ = f(t $_{_{
m D}}$); D: Duty cycle; $T_{_{
m S}}$ = 85 °C





Dimensional Drawing 9)



general tolerance ± 0.1 lead finish Sn

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Further Information:

Approximate Weight: 32.0 mg

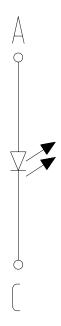
Corrosion test: Class: 3B

Test condition: 40°C / 90 % RH / 15 ppm H₂S / 14 days (stricter than IEC

60068-2-43)

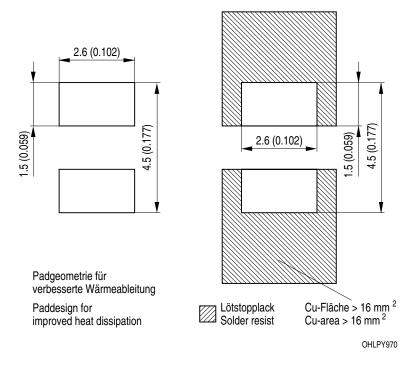


Electrical Internal Circuit

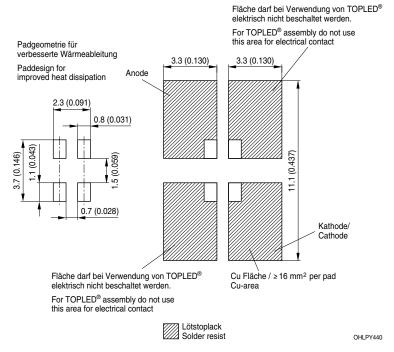




Recommended Solder Pad 9)



Recommended Solder Pad 9)

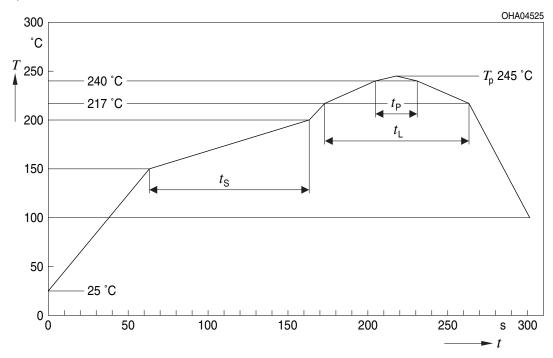


For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere. Package not suitable for ultra sonic cleaning.



Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



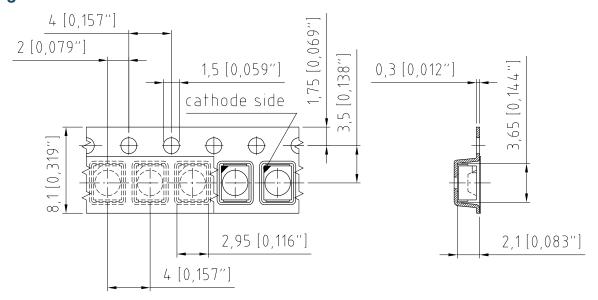
Profile Feature	Symbol	Symbol Pb-Free (SnAgCu) Assembly			Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat*) 25 °C to 150 °C			2	3	K/s
Time t_s T_{smin} to T_{smax}	t _s	60	100	120	S
Ramp-up rate to peak*) T_{Smax} to T_{P}			2	3	K/s
Liquidus temperature	T_{L}		217		°C
Time above liquidus temperature	$t_{\scriptscriptstyle \! \! \! \! \! \! \! \! \! \! \! \! \! \! \! \! \! \! \!$		80	100	S
Peak temperature	T _P		245	260	°C
Time within 5 °C of the specified peak temperature T _P - 5 K	t _P	10	20	30	S
Ramp-down rate* T _p to 100 °C			3	6	K/s
Time 25 °C to T _P				480	S

All temperatures refer to the center of the package, measured on the top of the component

 $^{^{\}star}$ slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range



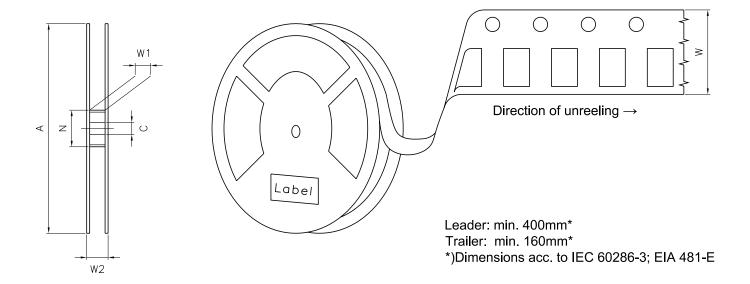
Taping 9)



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Tape and Reel 10)



Reel Dimensions

Α	W	N_{\min}	W_1	$W_{2 \text{ max}}$	Pieces per PU
180 mm	8 + 0.3 / - 0.1 mm	60 mm	8.4 + 2 mm	14.4 mm	2000



Barcode-Product-Label (BPL)



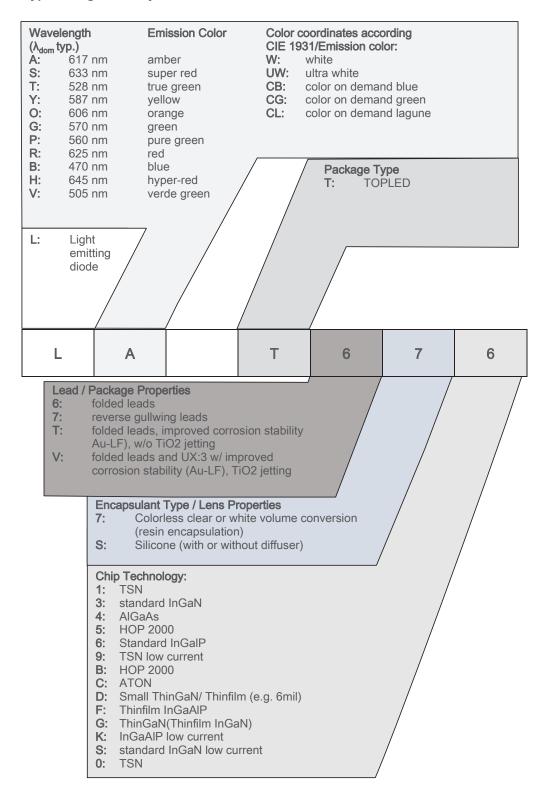
Dry Packing Process and Materials 9)



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.



Type Designation System



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Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet fall into the class exempt group (exposure time 10000 s). Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit www.osram-os.com/appnotes



Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on our website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

Our products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using our components in product safety devices/ applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and /or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.



Glossary

- Brightness: Brightness values are measured during a current pulse of typically 25 ms, with an internal reproducibility of ±8 % and an expanded uncertainty of ±11 % (acc. to GUM with a coverage factor of k = 3).
- 2) Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- Wavelength: The wavelength is measured at a current pulse of typically 25 ms, with an internal reproducibility of ±0.5 nm and an expanded uncertainty of ±1 nm (acc. to GUM with a coverage factor of k =
- 4) Forward Voltage: The forward voltage is measured during a current pulse of typically 8 ms, with an internal reproducibility of ±0.05 V and an expanded uncertainty of ±0.1 V (acc. to GUM with a coverage factor of k = 3).
- 5) **Thermal Resistance:** Rth max is based on statistic values (6σ) .
- 6) Thermal Resistance: RthJA results from mounting on PC board FR 4 (pad size 16 mm² per pad)
- 7) Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- 8) Characteristic curve: In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- 9) Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- Tape and Reel: All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.

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Revision	Revision History				
Version	Date	Change			
1.4	2019-09-24	Dimensional Drawing			
1.4	2019-10-14	Dimensional Drawing			
1.5	2020-06-01	Ordering Information Characteristics Forward Voltage Groups Electro - Optical Characteristics (Diagrams) Electrical Internal Circuit Schematic Transportation Box Dimensions of Transportation Box Glossary			
1.6	2022-05-25	New Layout			
1.7	2022-11-07	Derating (Diagrams)			

Applications



EU RoHS and China RoHS compliant product 此产品符合欧盟 RoHS 指令的要求; 按照中国的相关法规和标准, 不含有毒有害物质或元素。

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